R1130x SERIES

300mA LDO REGULATOR

OUTLINE

The R1130x Series are CMOS-based voltage regulator (VR) ICs. VR function has features of high ripple rejection, low dropout voltage, high output voltage accuracy, and ultra-low supply current. Each of these ICs consists of a voltage reference unit, an error amplifier, resistors for setting output voltage, and a current limit circuit. Each of the R1130xxxxA/B type includes also a chip enable circuit.

The output voltage of the R1130xxxxC type is adjustable with external resistors.

The output voltage of R1130xxxxA/B is fixed in the IC. Low supply current by the merit of CMOS process and built-in transistors with low ON-resistance make low dropout voltage. These regulators in the R1130x Series are remarkable improvement on the current regulators in terms of ripple rejection, input transient response, and load transient response. Maximum Output Current is large for its compact size.

Thus, the R1130x Series are suitable for power supply for CD-drives, DVD-drives, and so forth.

Since the packages for these ICs are the SOT-89-5 package or HSON-6 (Discontinued), high density mounting of the ICs on boards is possible.
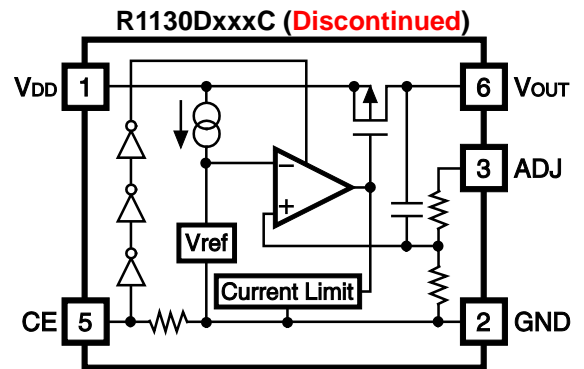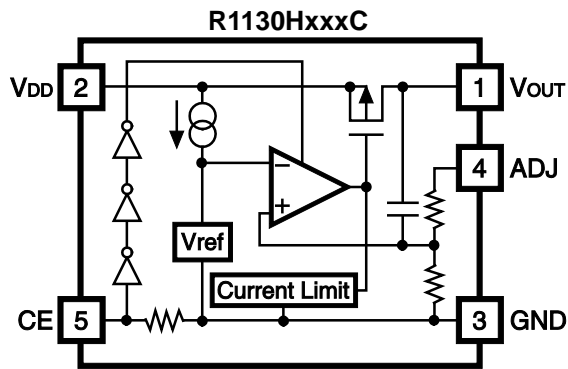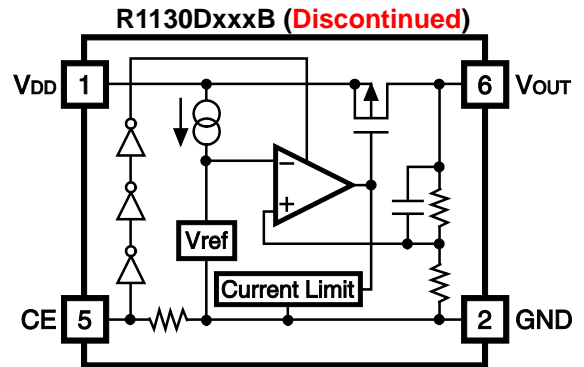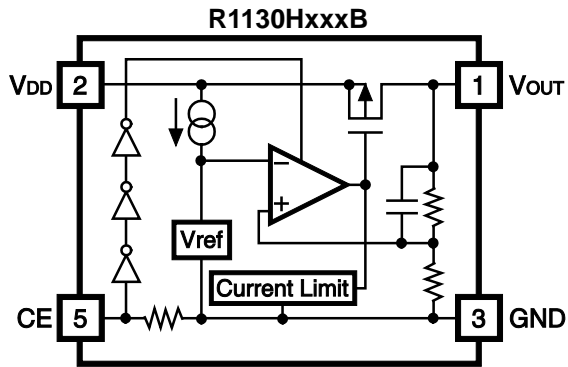
FEATURES

- Supply Current .... Typ. 50μA
- Standby Current .... Typ. 0.1μA (VR) for A type
- Ripple Rejection .... Typ. 60dB (f=1kHz) (VR)
- Output Current .... Min. 300mA ($V_{IN}=V_{OUT}+1V$)
- Output Voltage Range .... 1.5V to 5.0V (0.1V steps)

  Externally specified with the ADJUST pin

  (Reference Voltage 1.8V : C Version)

  (For other voltages, please refer to MARK INFORMATIONS.)
- Output Voltage Accuracy .... ±2.0%(VR) for A/B type,

  ±2.0% (Reference Voltage for adjustable VR) for C type
- Dropout Voltage .... Typ. 0.2V (I_{OUT}=100mA) (VR)
- Temperature-drift Coefficient of Output Voltage ...... ±100ppm/°C
- Absolute Maximum Voltage 9.0V
- Packages .... SOT-89-5, HSON-6 (Discontinued)
- Built-in Current Limit Circuit
- Internal Phase Compensation (small output capacitance such as 0.1μF Ceramic can be used with.)

APPLICATIONS

- Power source for CD-drives and DVD-drives, HDD.
- Local Power source for Notebook PC.

BLOCK DIAGRAMS

R1130HxxxA

R1130DxxxA (Discontinued)

R1130HxxxB

R1130DxxxB (Discontinued)

R1130HxxxC

R1130DxxxC (Discontinued)

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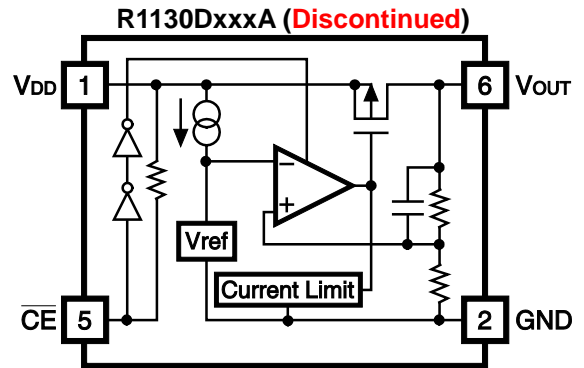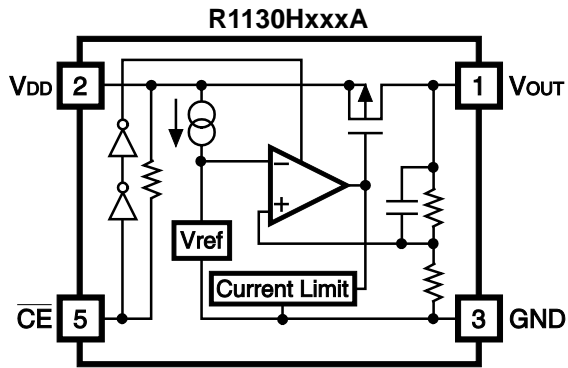
SELECTION GUIDE

The output voltage, CE pin polarity, package for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1130Dxx1∗-TR-FE	HSON-6 (Discontinued)	3,000 pcs	Yes	Yes
R1130Hxx1∗-T1-FE	SOT-89-5	1,000 pcs	Yes	Yes

xx: The output voltage can be designated in the range from 1.5V(15) to 5.0V(50) in 0.1V steps.
    (C Version is fixed at 00.)
    (For other voltages, please refer to MARK INFORMATIONS.)
 	
∗ : CE pin polarity are options as follows.
    (A) "L" active
    (B) "H" active
    (C) "H" active, with ADJUST pin.				

PIN CONFIGURATION

● **SOT-89-5**
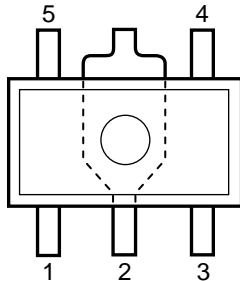
● **HSON-6**
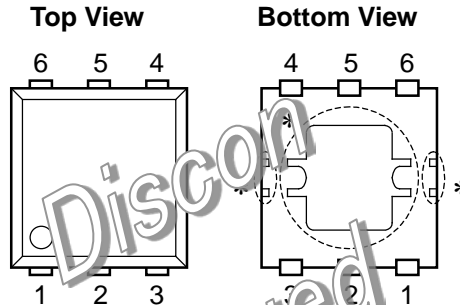
PIN DESCRIPTIONS

● **SOT-89-5**

Pin No.	Symbol	Description
1	V_{OUT}	Voltage Regulator Output Pin
2	V_{DD}	Input Pin
3	GND	Ground Pin
4	NC (A/B type)	No Connection
	ADJ (C type)	Adjustable Regulator feedback Input Pin (Connect to resistor voltage divider.)
5	$\overline{CE}$ (A type)or CE(B/D type)	Chip Enable Pin

● **HSON-6 (Discontinued)**

Pin No.	Symbol	Description
1	V_{DD}	Input Pin
2	GND	Ground Pin
3	NC (A/B type)	No Connection
	ADJ (C type)	Adjustable Regulator feedback Input Pin (Connect to resistor voltage divider.)
4	NC	No Connection
5	$\overline{CE}$ (A type)or CE(B/D type)	Chip Enable Pin
6	V_{OUT}	Voltage Regulator Output Pin

∗) Tab and tab suspension leads are V_{DD} level. (They are connected to the reverse side of the IC.)
   The tab is better to be connected to the V_{DD}, but leaving it open is also acceptable.
   The tab suspension leads should be open and do not connect to other wires or land patterns.

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ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	9.0	V
V_{CE}	Input Voltage ($\overline{CE}$ or CE Input Pin)	−0.3~9.0	V
V_{ADJ}	Input Voltage (ADJ Input Pin)	−0.3~9.0	V
V_{OUT}	Output Voltage	−0.3~V_{IN}+0.3	V
I_{OUT}	Output Current	450	mA
P_D	Power Dissipation (SOT-89-5)*	900	mW
	Power Dissipation (HSON-6)* (Discontinued)	900	
Topt	Operating Temperature Range	−40~85	°C
Tstg	Storage Temperature Range	−55~125	°C

∗) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS
Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS   (ELECTRICAL CHARACTERISTICS)
All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

● **R1130xxxxA**

Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{IN}	Input Voltage		2.5		8.0	V
I_{SS1}	Supply Current 1	$V_{IN}-V_{OUT}$=1.0V,V_{IN}=GND		50	100	μA
Istandby	Standby Current	$V_{IN}-V_{OUT}$=1.0V,V_{IN}=V_{CE}		0.1	1.0	μA
V_{OUT}	Output Voltage	$V_{IN}-V_{OUT}$=1.0V 1mA $\leq$ I_{OUT} $\leq$ 80mA	V_{OUT}× 0.980	Set V_{OUT}	V_{OUT}× 1.020	V
I_{OUT1}	Output Current	Refer to the table of Input Voltage by Set Output Voltage	300			mA
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	$V_{IN}-V_{OUT}$=1.0V 1mA $\leq$ I_{OUT} $\leq$ 80mA		40	80	mV
V_{DIF}	Dropout Voltage	I_{OUT}=100mA	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE			
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	I_{OUT}=80mA,Set V_{OUT}>2.0V: V_{OUT}+0.5V $\leq$ V_{IN} $\leq$ 8.0V Set $_{OUT}$ $\leq$ 1.9V: .5V $\leq$ V_{IN} $\leq$ 8.0V		0.1	0.2	%/V
RR	Ripple Rejection	f=1kHz Ripple 0.5Vp–p I_{OUT} = 80mA Set V_{OUT} $\geq$ 1.8V, V_{IN}–V_{OUT} = 1.0V Set V_{OUT} $\leq$ 1.7, V_{IN} = 2.8V		60		dB
$\Delta V_{OUT}/\Delta T_{opt}$	Output Voltage Temperature Coefficient	I_{OUT} = 30mA, V_{IN}–V_{OUT} = 1.0V $-40°C \leq T_{opt} \leq 85°C$		±100		ppm /°C
I_{SC}	Short Current Limit	Set V_{OUT} $\leq$ 3.9V,V_{OUT} = 0V		70		mA
		Set V_{OUT}>4.0V,V_{OUT} = 0V		50		
R_{PU}	$\overline{CE}$ Pull-up Resistance		2.5	5.0	10.0	MΩ
V_{CEH}	$\overline{CE}$ Input Voltage "H"	V_{IN}=2.5V	1.5		V_{IN}	V
V_{CEL}	$\overline{CE}$ Input Voltage "L"	V_{IN}=2.5V	0.00		0.25	V

● **R1130xxxxB**

Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{IN}	Input Voltage		2.5		8.0	V
I_{SS1}	Supply Current 1	V_{IN}-V_{OUT}=1.0V, V_{IN}=V_{CE}		50	100	μA
Istandby	Standby Current	V_{IN}-V_{OUT}=1.0V, V_{IN}=GND		0.1		μA
V_{OUT}	Output Voltage	V_{IN}-V_{OUT}=1.0V 1mA ≦ I_{OUT} ≦ 80mA	V_{OUT}× 0.980	Set V_{OUT}	V_{OUT}× 1.020	V
I_{OUT1}	Output Current	Refer to the table of Input Voltage by Set Output Voltage	300			mA
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	V_{IN}-V_{OUT}=1.0V 1mA ≦ I_{OUT} ≦ 80mA		40	80	mV
V_{DIF}	Dropout Voltage	I_{OUT}=100mA	Refer to the Table of Dropout Voltage by Set Output Voltage			
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	I_{OUT}=80mA, Set V_{OUT}>2.0V: V_{OUT}+0.5V ≦ V_{IN} ≦ 8.0V Set V_{OUT} ≦ 1.9V: 2.5V ≦ V_{IN} ≦ 8.0V		0.1	0.2	%/V
RR	Ripple Rejection	f=1kHz Ripple 0.5Vp–p I_{OUT} = 80mA Set V_{OUT} ≧ 1.8V, V_{IN}–V_{OUT} = 1.0V Set V_{OUT} ≦ 1.7, V_{IN} = 2.8V		60		dB
$\Delta V_{OUT}/\Delta T_{opt}$	Output Voltage Temperature Coefficient	I_{OUT} = 10mA, V_{IN}–V_{OUT} = 1.0V −40°C ≦ Topt ≦ 85°C		±100		ppm/°C
I_{SC}	Short Current Limit	Set V_{OUT} ≦ 3.9V, V_{OUT} = 0V		70		mA
		Set V_{OUT} ≧ 4.0V, V_{OUT} = 0V		50		
R_{PU}	Pull-down Resistance for CE pin		2.5	5.0	10.0	MΩ
V_{CEH}	CE Input Voltage "H"	V_{IN}=2.5V	1.5		V_{IN}	V
V_{CEL}	CE Input Voltage "L"	V_{IN}=2.5V	0.00		0.25	V

● **Dropout Voltage by Set Output Voltage**

Topt = 25°C

Output Voltage V_{OUT} (V)	Dropout Voltage V_{DIF} (V)	
	Typ.	**Max.**
V_{OUT} = 1.5	1.00	1.05
V_{OUT} = 1.6	0.90	0.95
V_{OUT} = 1.7	0.80	0.85
V_{OUT} = 1.8	0.70	0.75
V_{OUT} = 1.9	0.60	0.65
V_{OUT} = 2.0	0.50	0.60
V_{OUT} = 2.1	0.40	0.55
$2.2 \leq V_{OUT} \leq 2.5$	0.30	0.49
$2.6 \leq V_{OUT} \leq 3.3$	0.25	0.34
$3.4 \leq V_{OUT} \leq 5.0$	0.20	0.28

Dropout Voltage by Set Output Voltage

Topt = 25°C

Output Voltage V_{OUT} (V)	Input Voltage (V)
$1.5 \leq V_{OUT} \leq 1.9$	$V_{IN}=V_{OUT}+1.5V$
$2.0 \leq V_{OUT} \leq 2.7$	$V_{IN}=V_{OUT}+1.3V$
$2.8 \leq V_{OUT} \leq 5.0$	$V_{IN}=V_{OUT}+1.0V$

● **R1130xxxxC**

Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{IN}	Input Voltage		2.5		8.0	V
I_{SS1}	Supply Current	$V_{IN}-V_{OUT}=1.0V$, $V_{IN}=V_{CE}$		50	100	μA
Istandby	Standby Current	$V_{IN}-V_{OUT}=1.0V$, $V_{IN}=GND$		0.1	1.0	μA
V_{OUT}	Reference Voltage for Adjustable Voltage Regulator	$V_{OUT}=V_{ADJ}$,$V_{IN}-V_{OUT}=1.0V$ $I_{OUT}=80mA$	1.764	1.800	1.836	V
I_{OUT1}	Output Current	$V_{OUT}=V_{ADJ}$, $V_{IN}-V_{OUT}=1.5V$	300			mA
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	$V_{IN}=2.5V$, $V_{OUT}=V_{ADJ}$ $1mA \leq I_{OUT} \leq 80mA$		40	80	mV
V_{DIF}	Dropout Voltage	$I_{OUT}=100mA$, $V_{OUT}=V_{ADJ}$		0.1	0.2	V
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	$I_{OUT}=80mA$, $V_{OUT}=V_{ADJ}$ $2.5V \leq V_{IN} \leq 8.0V$		0.1	0.2	%/V
RR	Ripple Rejection	f=1kHz Ripple 0.5Vp–p $I_{OUT} = 80mA$,$V_{IN}–V_{OUT} = 1.0V$ $V_{OUT}=V_{ADJ}$,$I_{OUT}=80mA$		60		dB
$\Delta V_{OUT}/\Delta T_{opt}$	Output Voltage Temperature Coefficient	$I_{OUT} = 10mA$, $V_{IN}–V_{OUT} = 1.0V$ $-40°C \leq T_{opt} \leq 85°C$		±100		ppm /°C
I_{SC}	Short Current Limit	$V_{OUT} = 0V$		70		mA
R_{PU}	Pull-down Resistance for CE pin		2.5	5.0	10.0	MΩ
V_{CEH}	CE Input Voltage "H"	$V_{IN}=2.5V$	1.5		V_{IN}	V
V_{CEL}	CE Input Voltage "L"	$V_{IN}=2.5V$	0.00		0.25	V

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TEST CIRCUITS (Pin number is applied to R1130H Series)

- **R1130HxxxA**
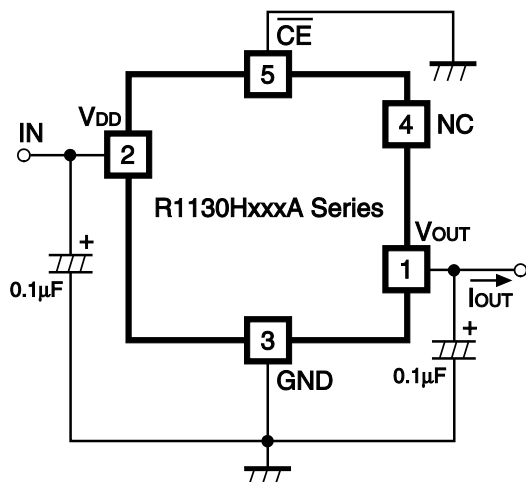
Fig.1 Standard test Circuit
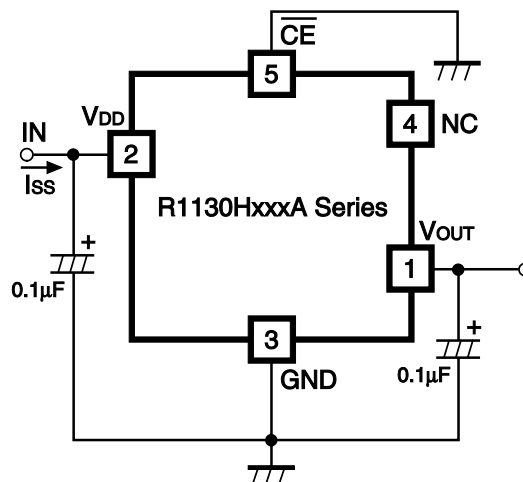
Fig.2 Supply Current Test Circuit
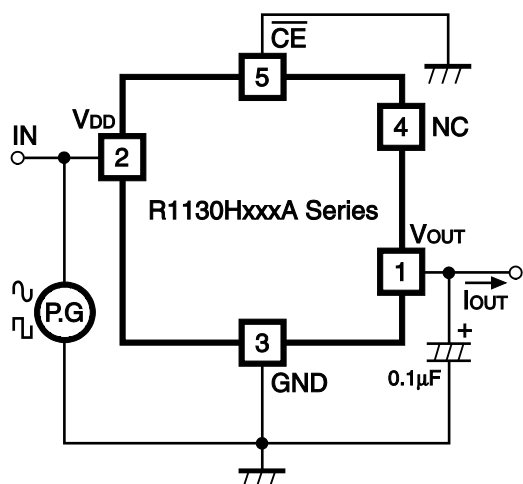
Fig.3 Ripple Rejection, Line Transient Response Test Circuit
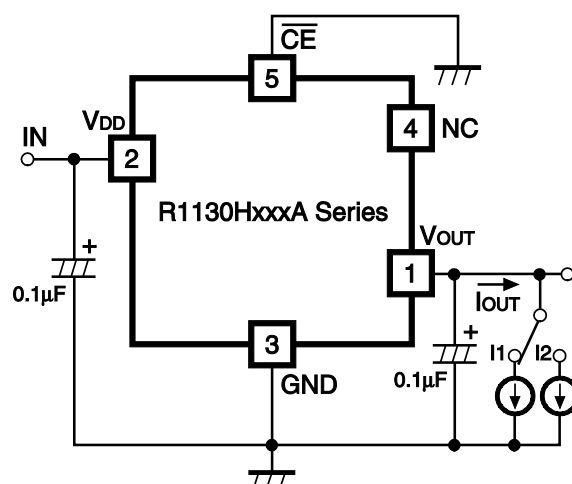
Fig.4 Load Transient Response Test Circuit

● **R1130HxxxB**
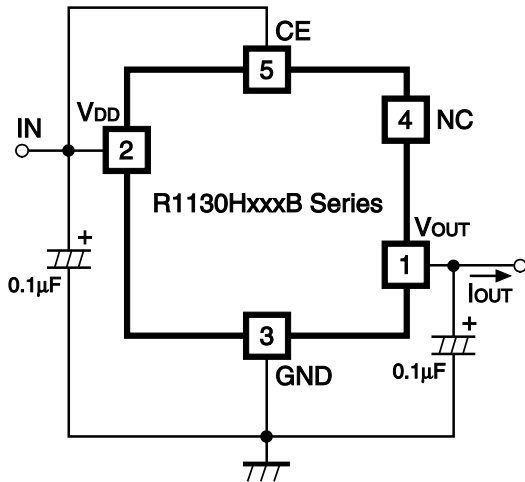
Fig.1 Standard test Circuit
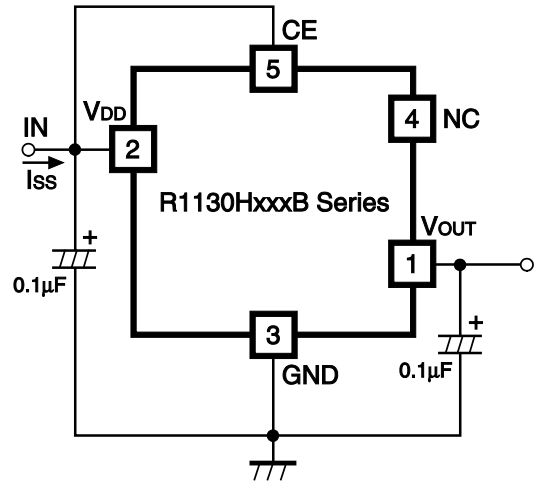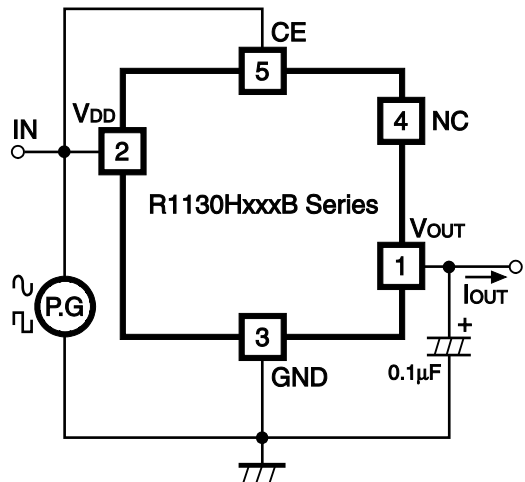
Fig.2 Supply Current Test Circuit

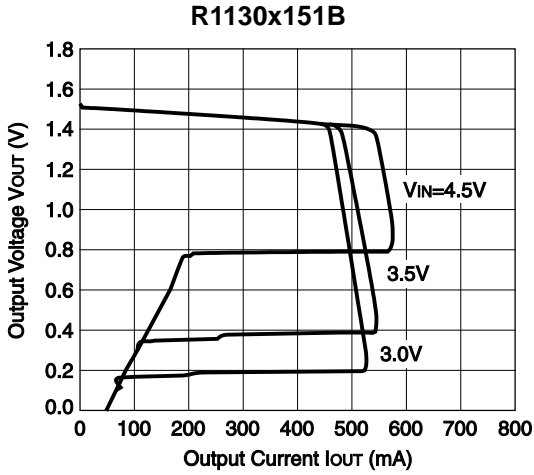**Fig.3 Test Circuit for Ripple Rejection and Input Transient Response**

Fig.4 Test Circuit for Load Transient Response

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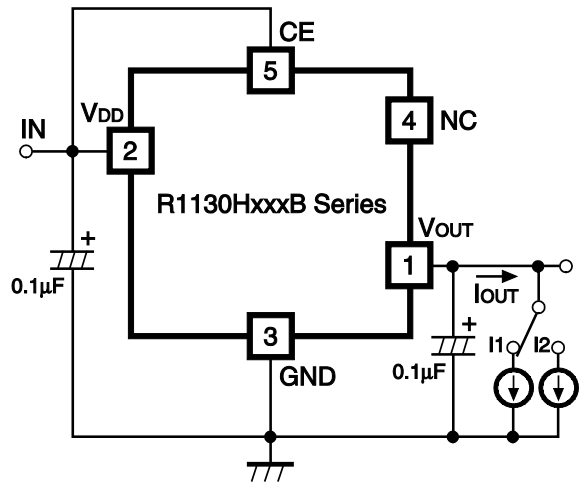
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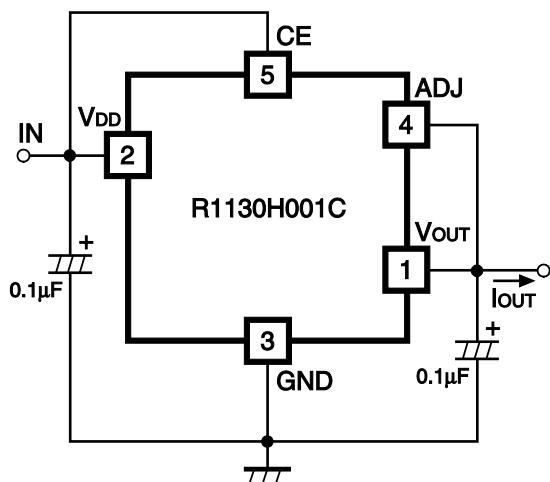
Fig.1 Standard test Circuit
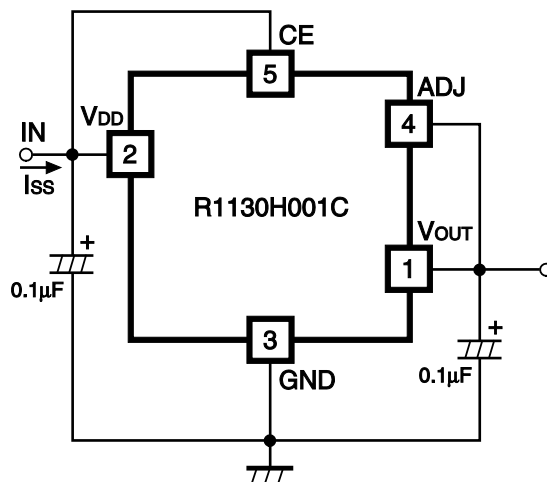
Fig.2 Test Circuit Supply Current
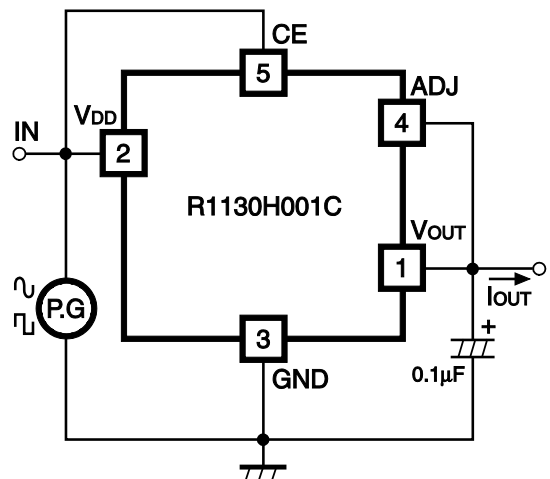
Fig.3 Test Circuit for Ripple Rejection and Input Transient Response
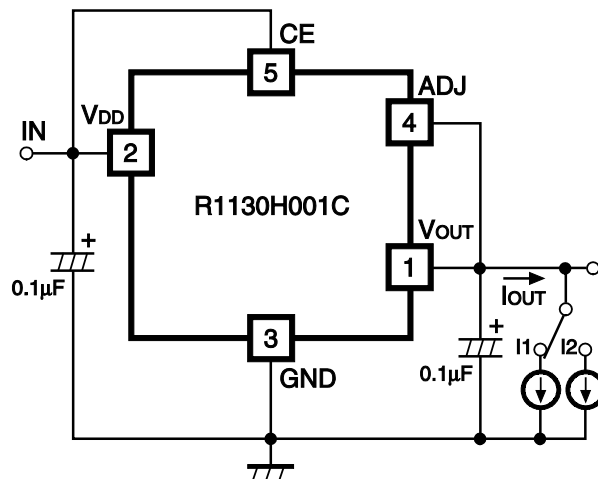
Fig.4 Test Circuit for Load Transient Response

TYPICAL CHARACTERISTICS

1) Output Voltage vs. Output Current (Topt=25°C)

R1130x151B

R1130x331B

R1130x501B
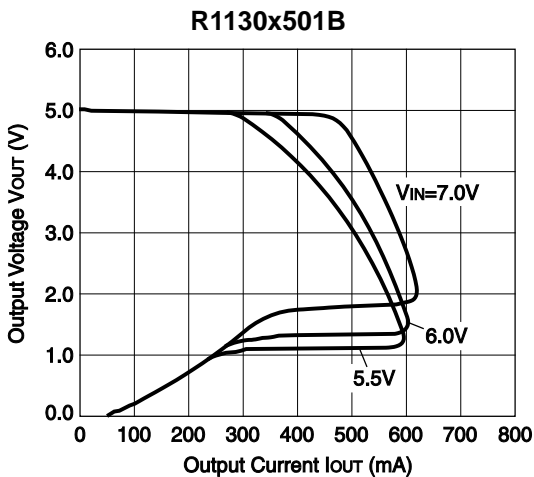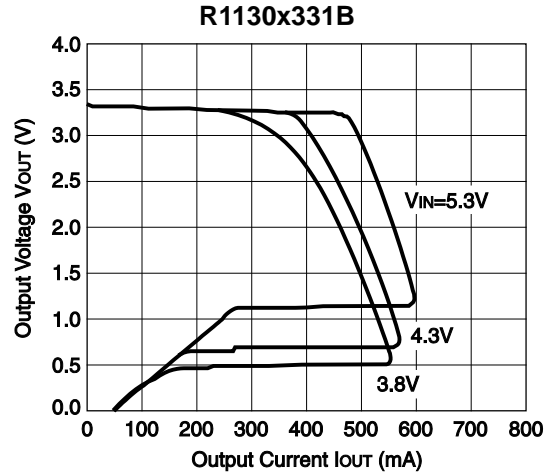
2) Input Voltage vs. Output Voltage (Topt=25°C)

R1130x151B

R1130x331B

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R1130x501B

Output Voltage V_{OUT} (V) vs. Input Voltage V_{IN} (V), $I_{OUT}=1mA$, 80mA
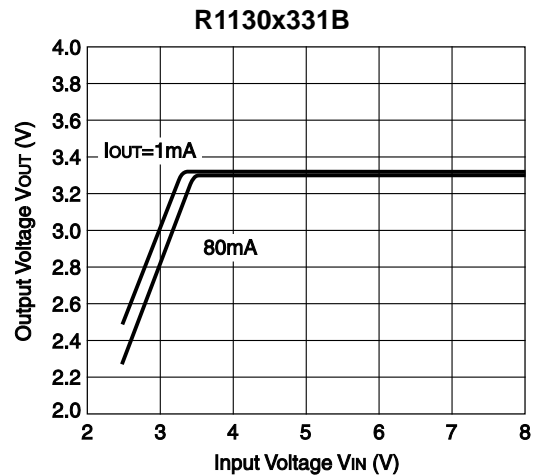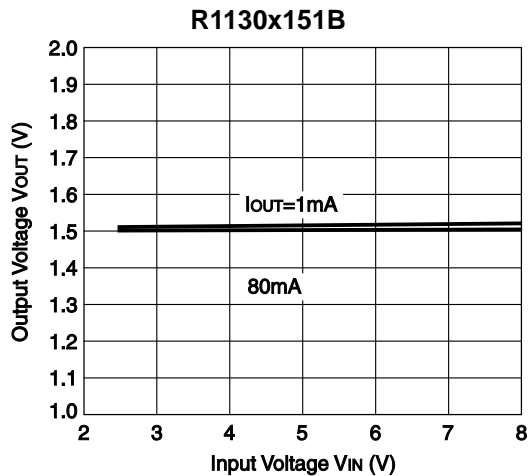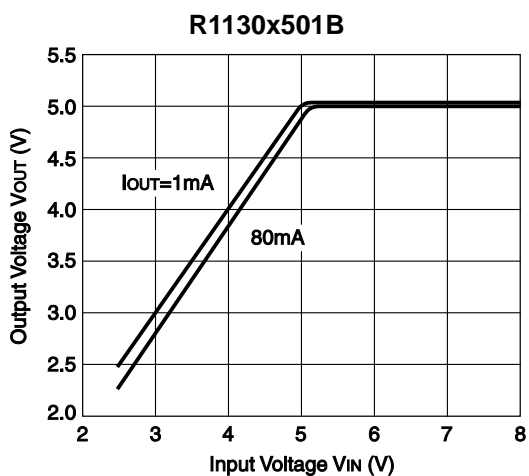
3) Dropout Voltage vs. Output Current

R1130x151B

Dropout Voltage V_{DIF} (V) vs. Output Current I_{OUT} (mA), Topt=85°C, 25°C, -40°C

R1130x331B

Dropout Voltage V_{DIF} (V) vs. Output Current I_{OUT} (mA), Topt=85°C, 25°C, -40°C

R1130x501B

Dropout Voltage V_{DIF} (V) vs. Output Current I_{OUT} (mA), Topt=85°C, 25°C, -40°C
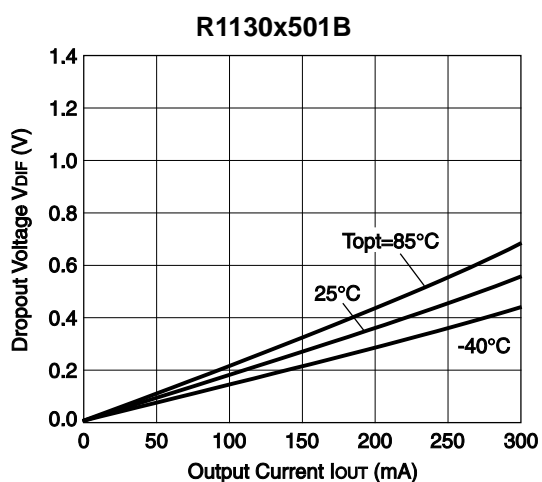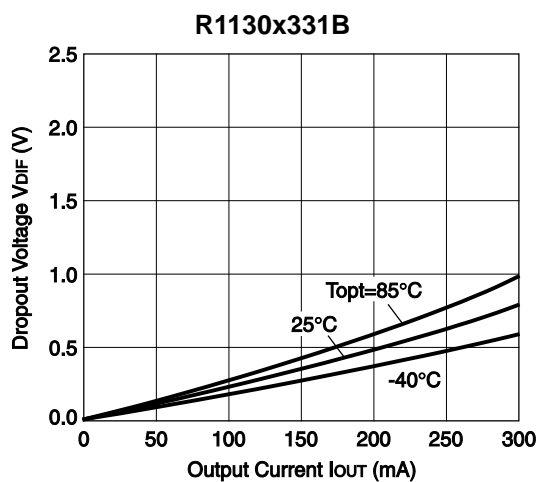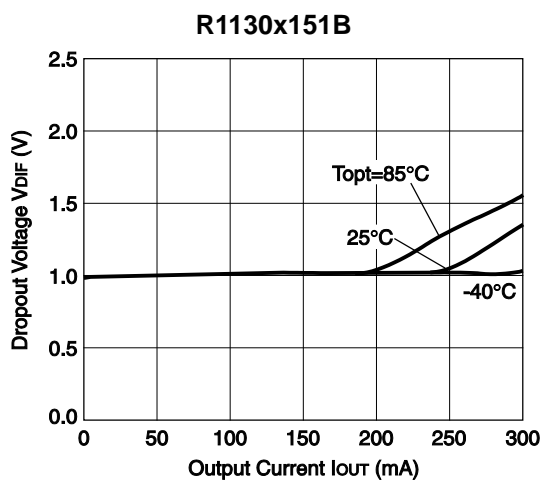
4) Output Voltage vs. Temperature

R1130x151B

I_{OUT}=80mA

Output Voltage V_{OUT} (V) vs. Temperature Topt (°C)

(Y-axis: 1.40 to 1.60, X-axis: -50 to 100)

R1130x331B

I_{OUT}=80mA

Output Voltage V_{OUT} (V) vs. Temperature Topt (°C)

(Y-axis: 3.20 to 3.40, X-axis: -50 to 100)

R1130x501B

I_{OUT}=80mA

Output Voltage V_{OUT} (V) vs. Temperature Topt (°C)

(Y-axis: 4.90 to 5.10, X-axis: -50 to 100)
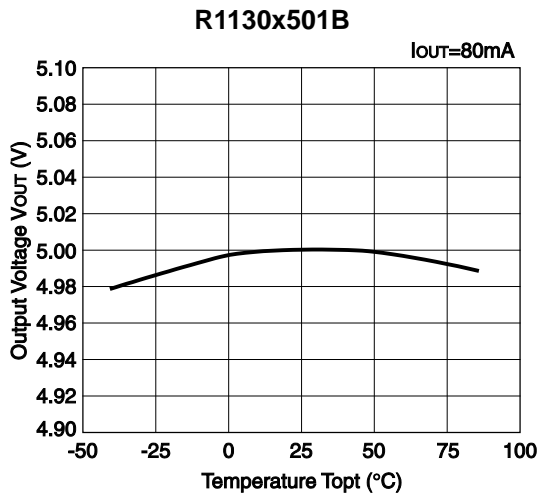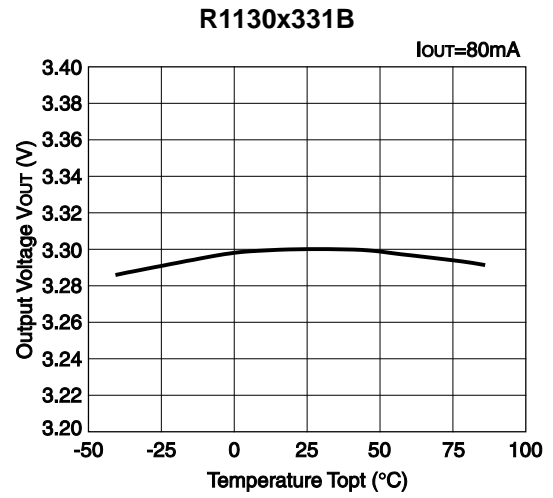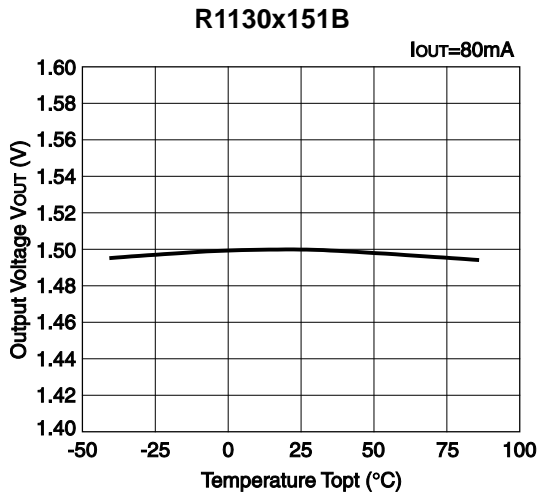
5) Supply Current vs. Input Voltage (Topt=25°C)

R1130x151B

Supply Current I_{SS} (µA) vs. Input Voltage V_{IN} (V)

(Y-axis: 0 to 80, X-axis: 2 to 8)

R1130x331B

Supply Current I_{SS} (µA) vs. Input Voltage V_{IN} (V)

(Y-axis: 0 to 80, X-axis: 2 to 8)

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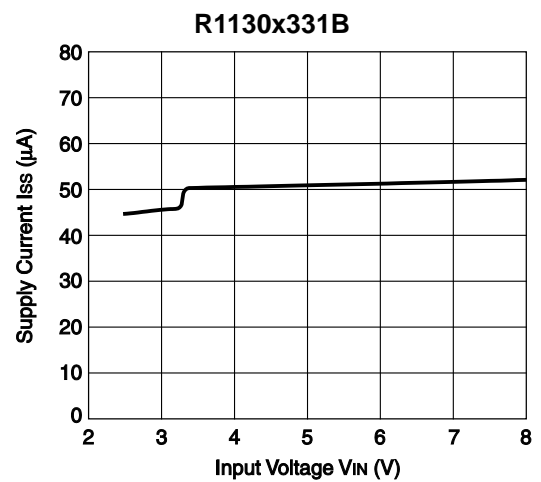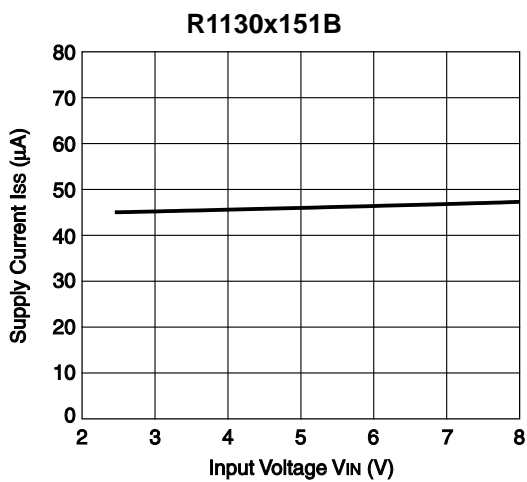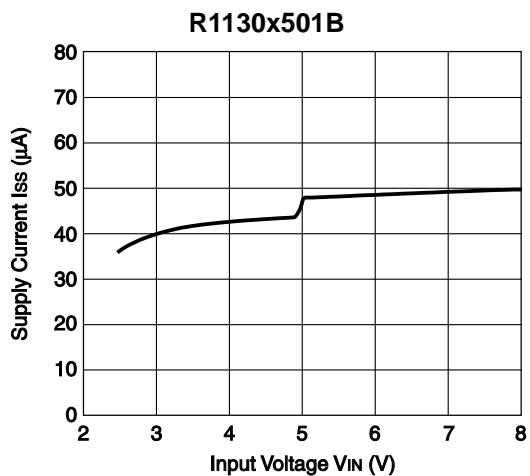
R1130x501B

6) Supply Current vs. Temperature

R1130x151B

V$_{IN}$=2.5V

R1130x331B

V$_{IN}$=4.3V

R1130x501B

V$_{IN}$=6.0V
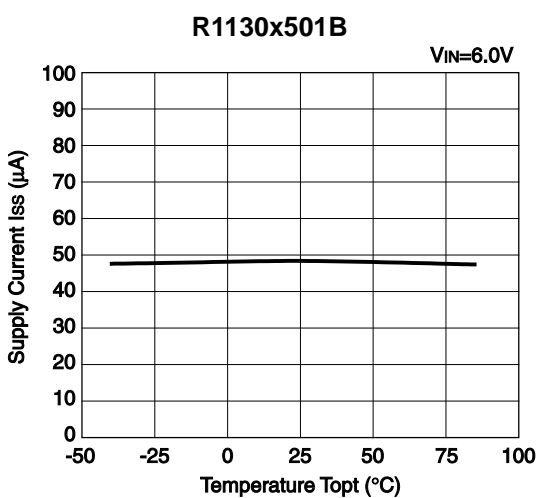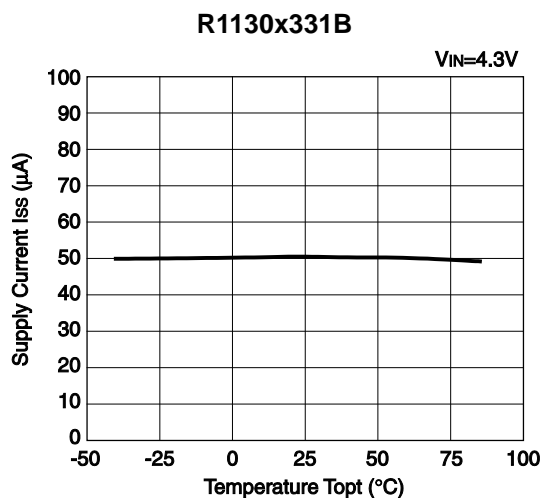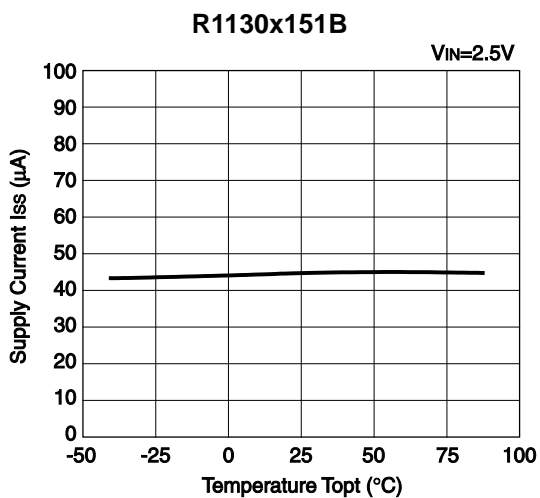
7) Ripple Rejection vs. Frequency

R1130x151B

$V_{IN}=V_{OUT}+1V, 0.5Vp\text{-}p$
$C_{OUT}=0.1\mu F$

R1130x331B

$V_{IN}=V_{OUT}+1V, 0.5Vp\text{-}p$
$C_{OUT}=0.1\mu F$

R1130x501B

$V_{IN}=V_{OUT}+1V, 0.5Vp\text{-}p$
$C_{OUT}=0.1\mu F$
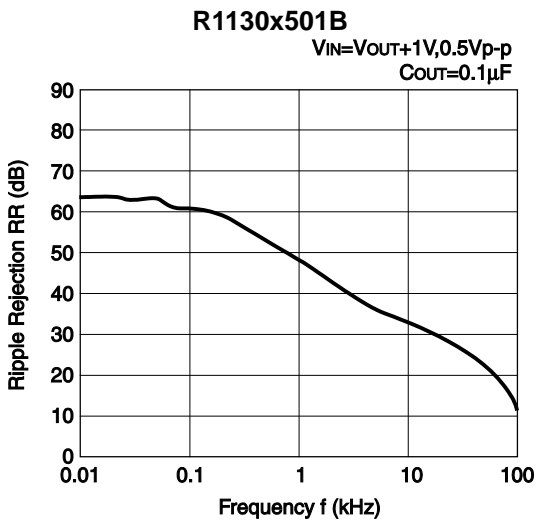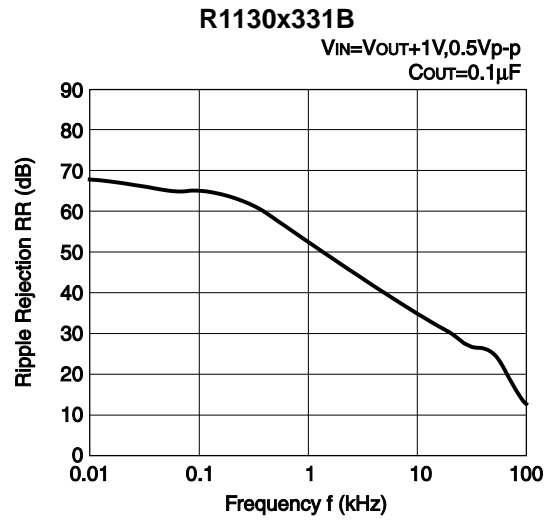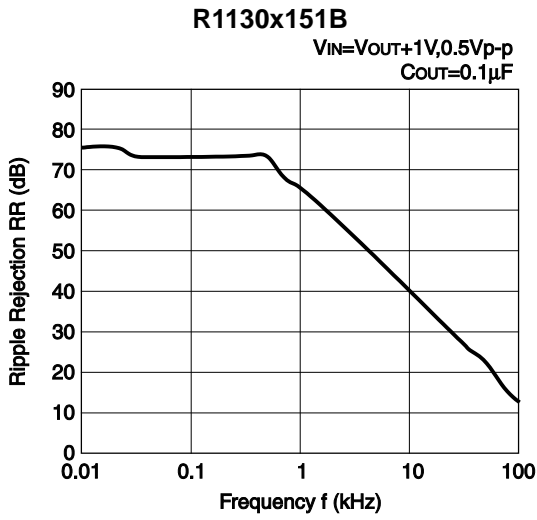
8) Ripple Rejection vs. Input Voltage

R1130x151B

R1130x331B

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R1130x501B

9) Input Transient Response

R1130x151B

$I_{OUT}=80mA$
$tr=tf=5\mu s$
$C_{OUT}=0.1\mu F$

R1130x151B

$I_{OUT}=80mA$
$tr=tf=5\mu s$
$C_{OUT}=0.1\mu F$

R1130x501B

I_{OUT}=80mA
t_r=t_f=5μs
C_{OUT}=0.1μF

10) Load Transient Response

R1130x151B

V_{IN}=2.5V
C_{IN}=1.0μF
C_{OUT}=0.1μF

R1130x331B

V_{IN}=4.3V
C_{IN}=1.0μF
C_{OUT}=0.1μF

Nisshinbo Micro Devices Inc.

R1130x501B

V_{IN}=6.0V
C_{IN}=1.0μF
C_{OUT}=0.1μF
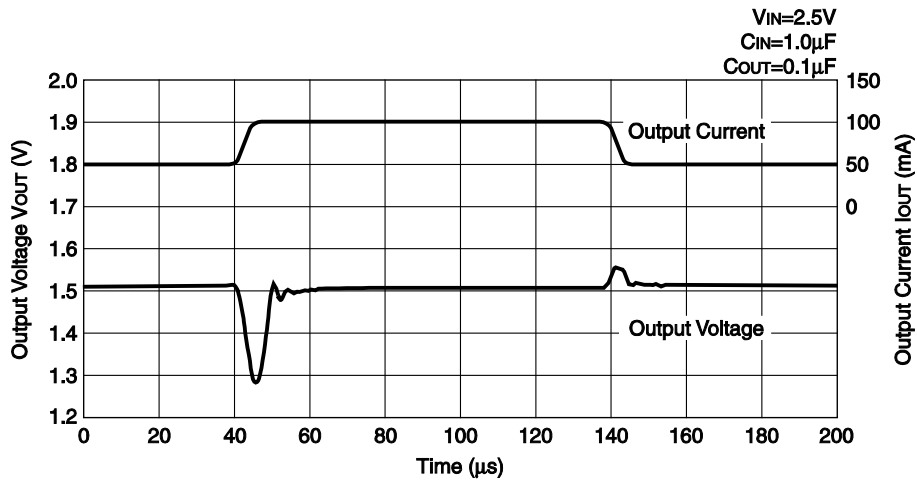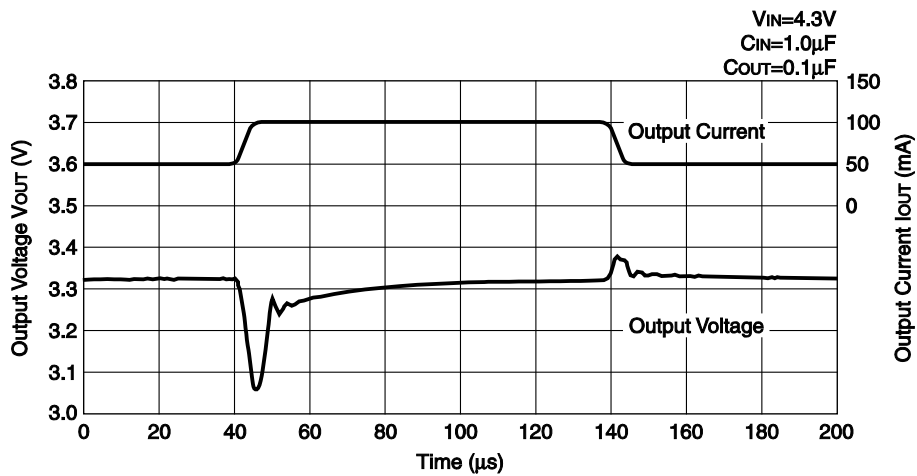
APPENDIX

* Technical Notes on Output Voltage Setting of C type

Figure 1. Adjustable Regulator (C type)
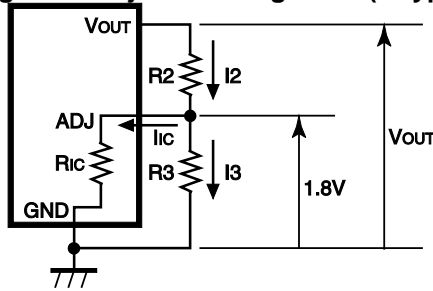
The Output Voltage of Regulator in R1130xxxxC may be adjustable for any output voltage between its 1.8V reference and its V_{DD} setting level. An external pair of resistors is required, as shown in Figure 1.

The complete equation for the output voltage is described step by step as follows;

$$I2=I_{IC}+I3 \quad\text{·· (1)}$$
$$I3=1.8/R3 \quad\text{·· (2)}$$

Thus,

$$I2=I_{IC}+1.8/R3 \quad\text{··· (3)}$$

Therefore,

$$V_{OUT}=1.8+R2\times I2 \quad\text{··· (4)}$$

Put Equation (3) into Equation (4), then

$$V_{OUT}=1.8+R2\times(I_{IC}+1.8/R3)$$
$$=1.8\times(1+R2/R3)+R2\times I_{IC} \quad\text{·································· (5)}$$

In 2nd term, or $R2\times I_{IC}$ will produce an error in V_{OUT}.

In Equation (5),

$$I_{IC}=1.8/R_{IC} \quad\text{··· (6)}$$
$$R2\times I_{IC}=R2\times 1.8/R_{IC}$$
$$=1.8\times R2/R_{IC} \quad\text{··· (7)}$$

For better accuracy, choosing R2 ($<<R_{IC}$) reduces this error.

* Adjustable Resistor Dependence of Output Voltage

R1130x001C
R3=10kΩ, Topt=25°C

R1130x001C
R3=100kΩ, Topt=25°C

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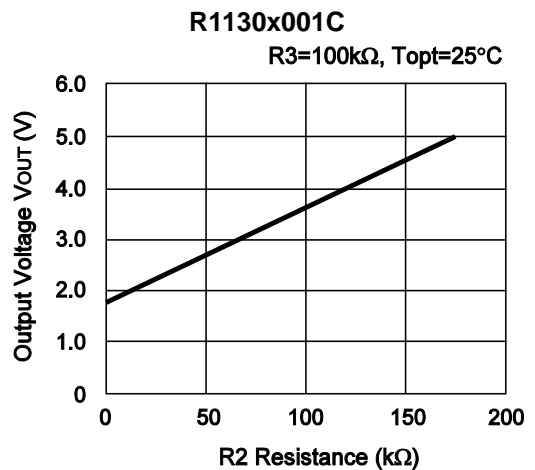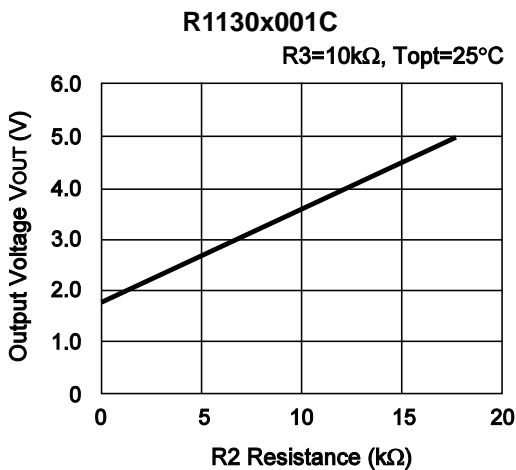
TYPICAL APPPLICATION

R1130xxxxA
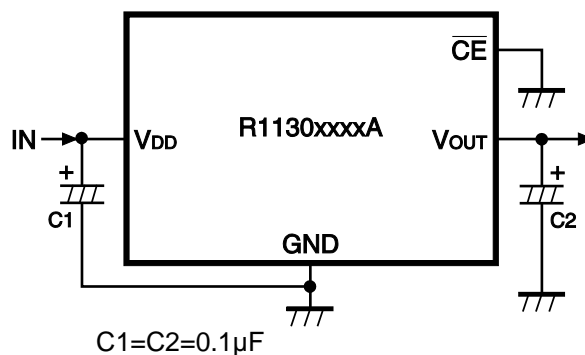
C1=C2=0.1μF

R1130xxxxB
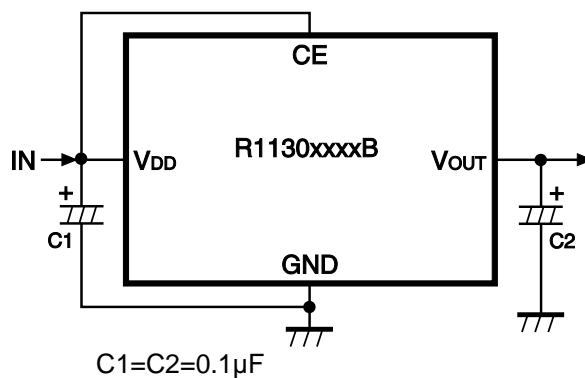
C1=C2=0.1μF

R1130xxxxC
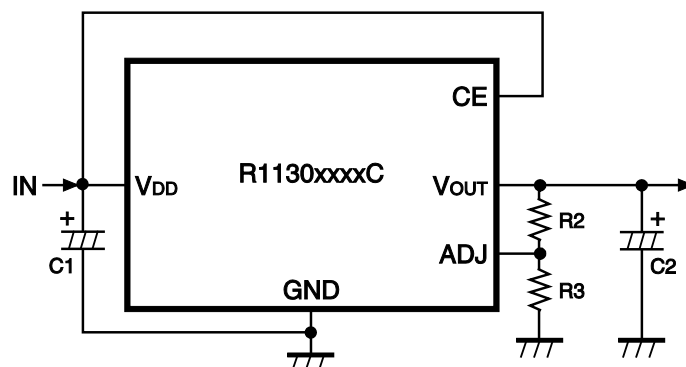
C1=C2=0.1μF, R2, R3: Refer to the Technical Notes on Output Voltage setting of C type.

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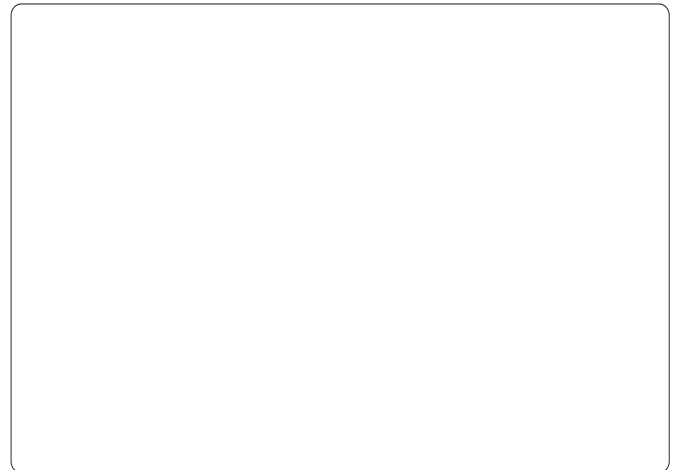
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